

Ultra Low Noise, Low Current E-PHEMT

0.45-6GHz

Product Features

- Low Noise Figure, 0.5 dB
- Gain, 16 dB at 2 GHz
- High Output IP3, +25 dBm
- Output Power at 1dB comp., +18 dBm
- Low Current, 15mA
- Wide bandwidth
- External biasing and matching required
- May be used as replacement ^{a,b} for Avago ATF-55143



SAV-551+

CASE STYLE: MMM1362
PRICE: \$0.99 ea. QTY. (10-49)

Typical Applications

- Cellular
- ISM
- GSM
- WCDMA
- WiMax
- WLAN
- UNII and HIPERLAN

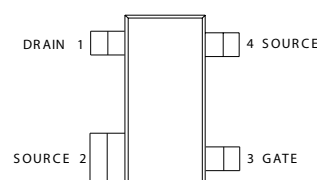
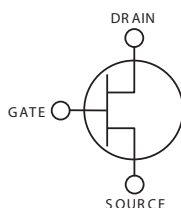
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

General Description

SAV-551+ is an ultra-low noise, high IP3 transistor device, manufactured using E-PHEMT* technology enabling it to work with a single positive supply voltage. It has outstanding Noise Figure, particularly below 2.5 GHz, and when combining this noise figure with high IP3 performance in a single device it makes it an ideal amplifier for demanding base station applications. We offer these units assembled into a complete module, 50Ω in/out, noise matched and fully specified. For more information please see our TAMP family of models on our web site.

simplified schematic and pin description



SOT-343 (SC-70) PACKAGE

Function	Pin Number	Description
Source	2 & 4	Source terminal, normally connected to ground
Gate	3	Gate used for RF input
Drain	1	Drain used for RF output

* Enhancement mode Pseudomorphic High Electron Mobility Transistor.

a. Suitability for model replacement within a particular system must be determined by and is solely the responsibility of the customer based on, among other things, electrical performance criteria, stimulus conditions, application, compatibility with other components and environmental conditions and stresses.

b. The Avago ATF-55143 part number is used for identification and comparison purposes only.

Mini-Circuits
ISO 9001 ISO 14001 AS 9100 CERTIFIED

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Electrical Specifications at $T_{AMB}=25^{\circ}\text{C}$, Frequency 0.45 to 6 GHz

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
DC Specifications						
V_{GS}	Operational Gate Voltage	$V_{DS}=3\text{V}$, $I_{DS}=15\text{ mA}$	0.22	0.34	0.46	V
V_{TH}	Threshold Voltage	$V_{DS}=3\text{V}$, $I_{DS}=4\text{ mA}$	0.18	0.26	0.38	V
I_{DSS}	Saturated Drain Current	$V_{DS}=3\text{V}$, $V_{GS}=0\text{ V}$		1.0	5.0	μA
G_M	Transconductance	$V_{DS}=3\text{V}$, $G_m=\Delta I_{DS}/\Delta V_{GS}$ $\Delta V_{GS}=V_{GS1}-V_{GS2}$ $V_{GS1}=V_{GS}$ at $I_{DS}=15\text{ mA}$ $V_{GS2}=V_{GS1}+0.05\text{V}$	215	251	285	mS
I_{GSS}	Gate leakage Current	$V_{GD}=V_{GS}=-3\text{V}$			95	μA
RF Specifications, $Z_0=50\text{ Ohms}$ (Figure 1)						
NF ⁽¹⁾	Noise Figure	$V_{DS}=3\text{V}$, $I_{DS}=15\text{ mA}$ $V_{DS}=4\text{V}$, $I_{DS}=15\text{ mA}$	f=0.9 GHz f=2.0 GHz f=3.9 GHz f=5.8 GHz	0.5 0.6 1.0 1.8	0.9	dB
Gain	Gain	$V_{DS}=3\text{V}$, $I_{DS}=15\text{ mA}$ $V_{DS}=4\text{V}$, $I_{DS}=15\text{ mA}$	f=0.9 GHz f=2.0 GHz f=3.9 GHz f=5.8 GHz	14.4 15.9 11.2 7.6	17.5	dB
OIP3	Output IP3	$V_{DS}=3\text{V}$, $I_{DS}=15\text{ mA}$ $V_{DS}=4\text{V}$, $I_{DS}=15\text{ mA}$	f=0.9 GHz f=2.0 GHz f=3.9 GHz f=5.8 GHz	20.0 22.4 24.3 26.9 28.5		dBm
P1dB ⁽²⁾	Power output at 1 dB Compression	$V_{DS}=3\text{V}$, $I_{DS}=15\text{ mA}$ $V_{DS}=4\text{V}$, $I_{DS}=15\text{ mA}$	f=0.9 GHz f=2.0 GHz f=3.9 GHz f=5.8 GHz	16.0 17.2 17.5 18.5 17.5		dBm

Absolute Maximum Ratings⁽³⁾

Symbol	Parameter	Max.	Units
V_{DS} ⁽⁴⁾	Drain-Source Voltage	5	V
V_{GS} ⁽⁴⁾	Gate-Source Voltage	-5 to 0.7	V
V_{GD} ⁽⁴⁾	Gate-Drain Voltage	-5 to 0.7	V
I_{DS} ⁽⁴⁾	Drain Current	100	mA
I_{GS}	Gate Current	2	mA
P_{DISS}	Total Dissipated Power	360	mW
P_{IN} ⁽⁵⁾	RF Input Power	17	dBm
T_{CH}	Channel Temperature	150	$^{\circ}\text{C}$
T_{OP}	Operating Temperature	-40 to 85	$^{\circ}\text{C}$
T_{STG}	Storage Temperature	-65 to 150	$^{\circ}\text{C}$
θ_{JC}	Thermal Resistance	160	$^{\circ}\text{C}/\text{W}$

Notes:

- (1) Includes test board loss (tested on Mini-Circuits TB-471+ test board)
- (2) Drain current was allowed to increase during compression measurements.
- (3) Operation of this device above any one of these parameters may cause permanent damage.
- (4) Assumes DC quiescent conditions.
- (5) I_{GS} is limited to 2 mA during test.

Characterization Test Circuit

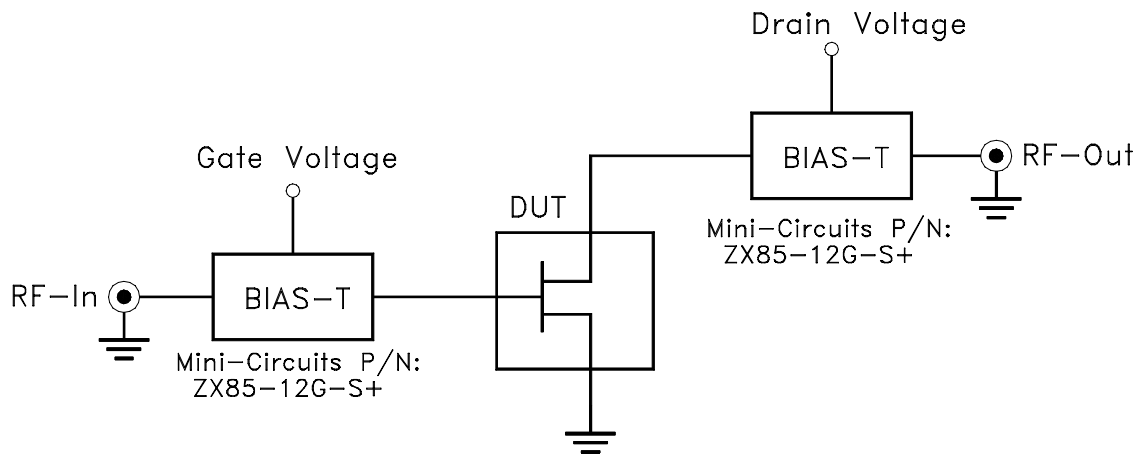


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Test Board TB-471+) Gain, Output power at 1dB compression (P1 dB) and output IP3 (OIP3) are measured using R&S Network Analyzer ZVA-24. Noise Figure measured using Agilent Noise Figure meter N8975A and Noise Source N4000A.

Conditions:

1. Drain voltage (with reference to source, V_{DS})= 3 or 4V as shown.
2. Gate Voltage (with reference to source, V_{GS}) is set to obtain desired Drain-Source current (IDS) as shown in graphs or specification table.
3. Gain: Pin= -25dBm
4. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.
5. No external matching components used.

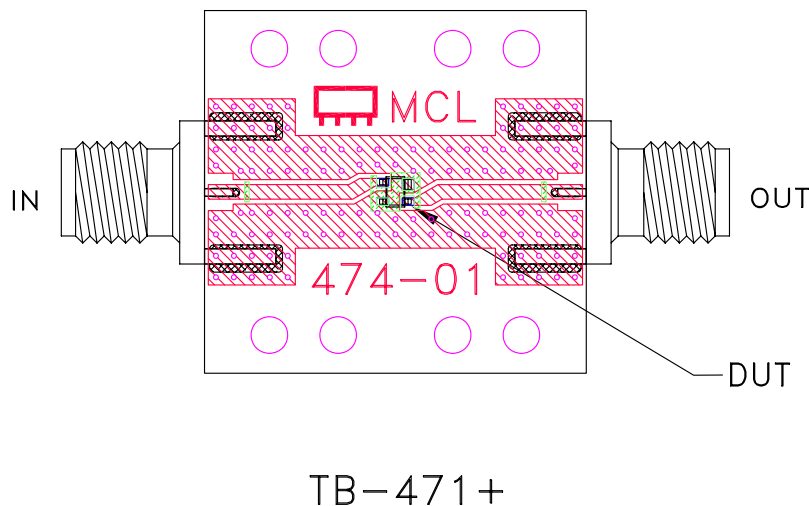
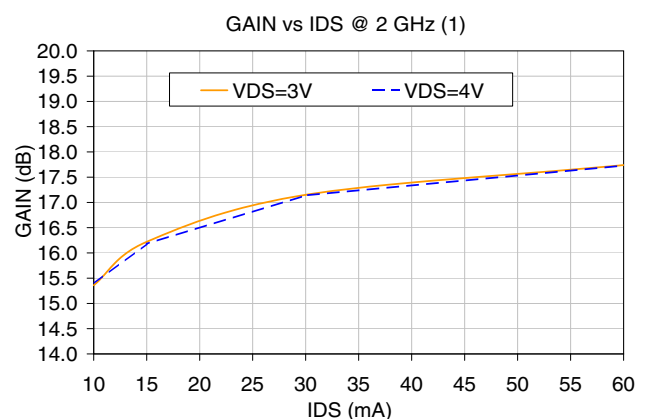
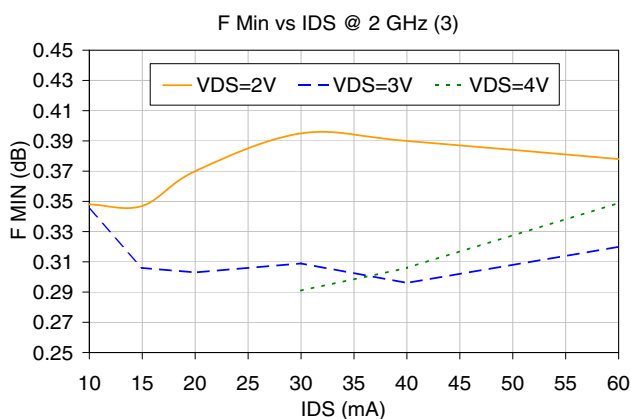
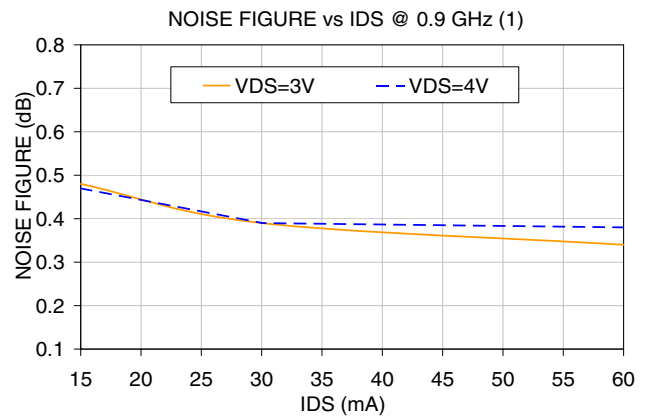
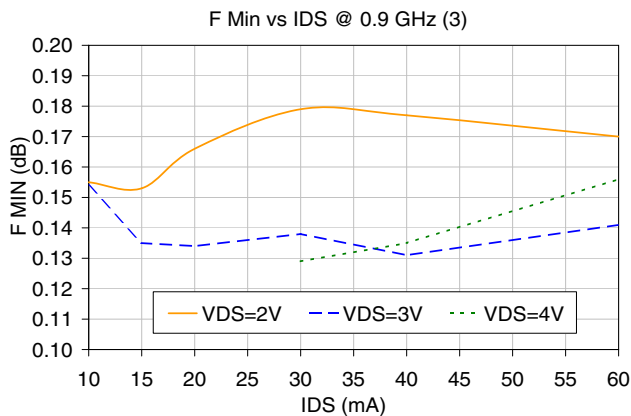
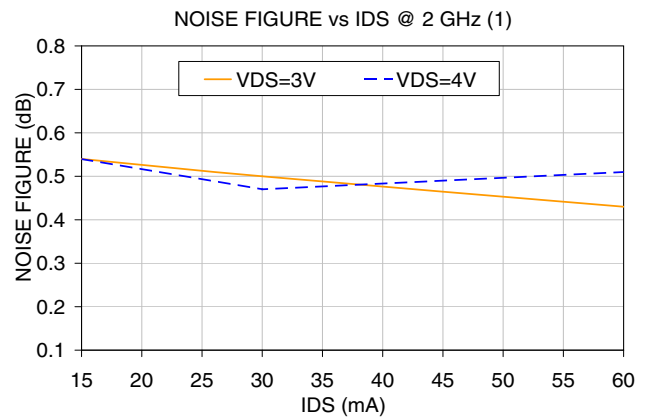
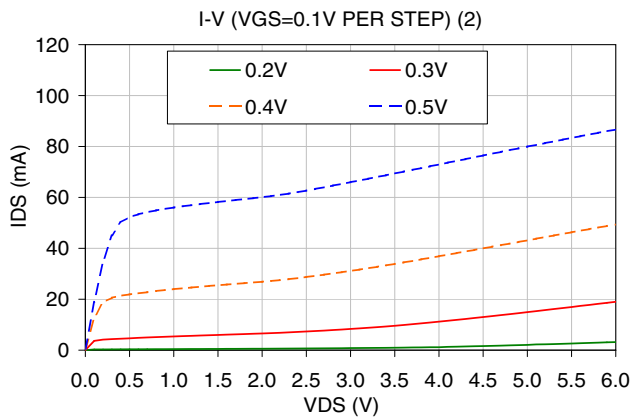


Fig 2. Test Board used for characterization, Mini-Circuits P/N TB-471+ (Material: Rogers 4350, Thickness: 0.02")

Typical Performance Curves



- (1) Includes test board loss, set-up and conditions per Figure 1.
- (2) Measured using HP4155B semiconductor parameter analyzer.
- (3) F Min is minimum Noise Figure.
- (4) Drain current was allowed to increase during compression measurement.

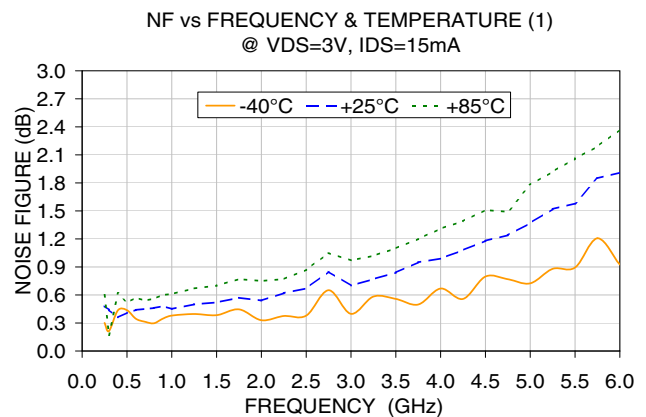
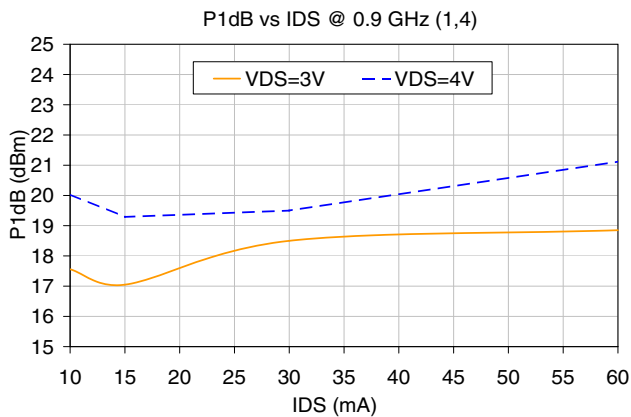
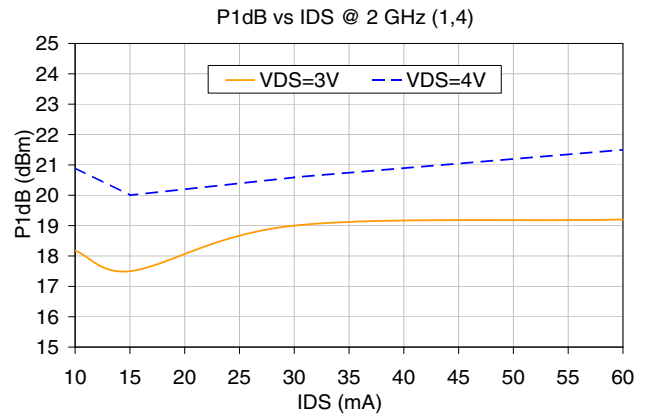
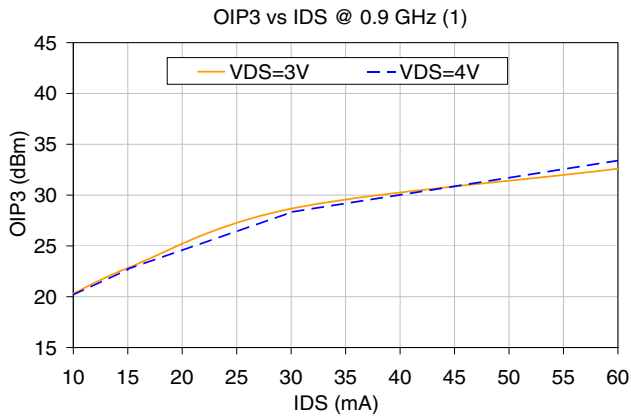
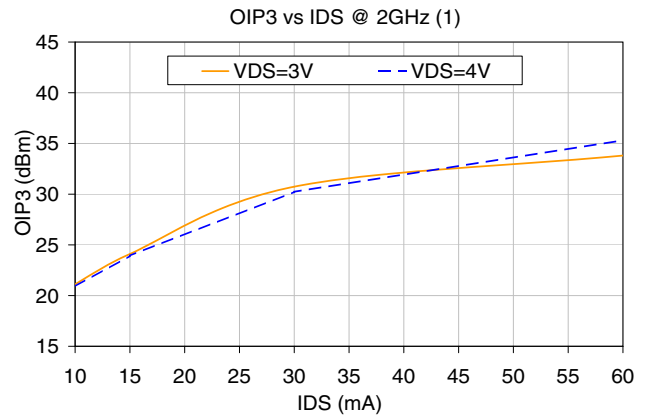
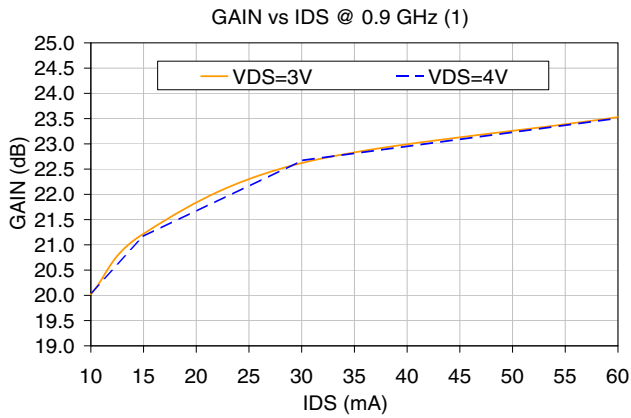


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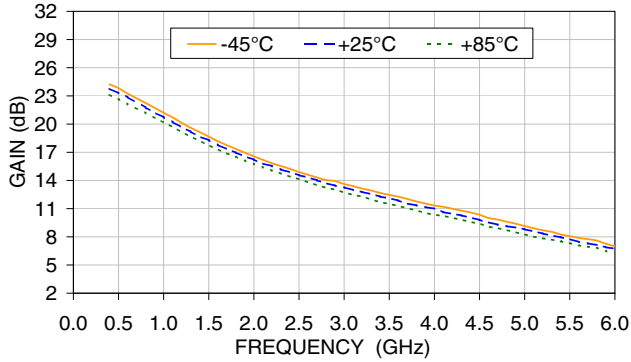


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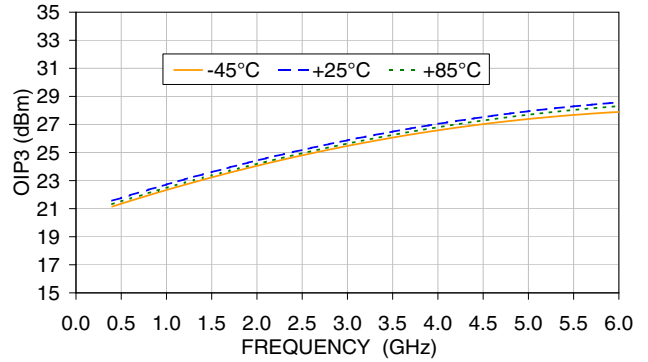
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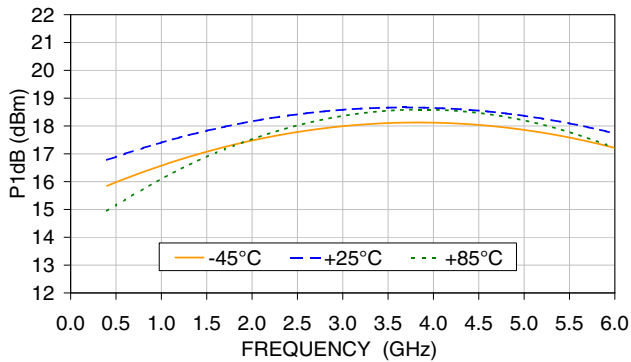
GAIN vs FREQUENCY & TEMPERATURE (1)
@ VDS=3V, IDS=15mA



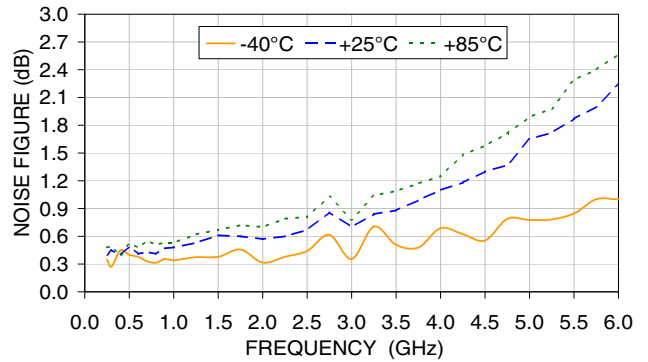
OIP3 vs FREQUENCY & TEMPERATURE (1)
@ VDS=3V, IDS=15mA



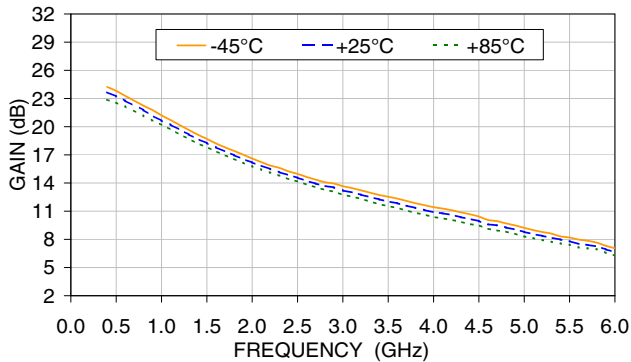
P1dB vs FREQUENCY & TEMPERATURE (1,2)
@ VDS=3V, IDS=15mA



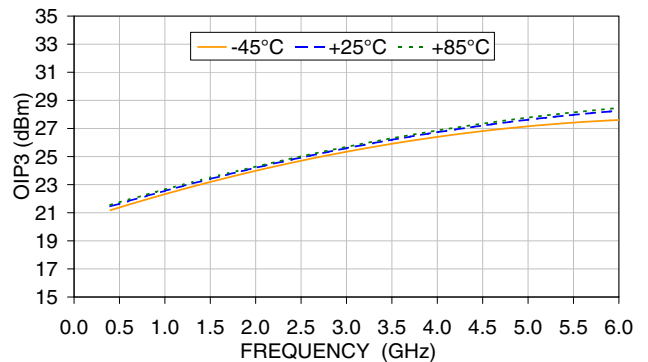
NF vs FREQUENCY & TEMPERATURE (1)
@ VDS=4V, IDS=15mA



GAIN vs FREQUENCY & TEMPERATURE (1)
@ VDS=4V, IDS=15mA



OIP3 vs FREQUENCY & TEMPERATURE (1)
@ VDS=4V, IDS=15mA



- (1) Includes test board loss, set-up and conditions per Figure 1.
- (2) Measured using HP4155B semiconductor parameter analyzer.
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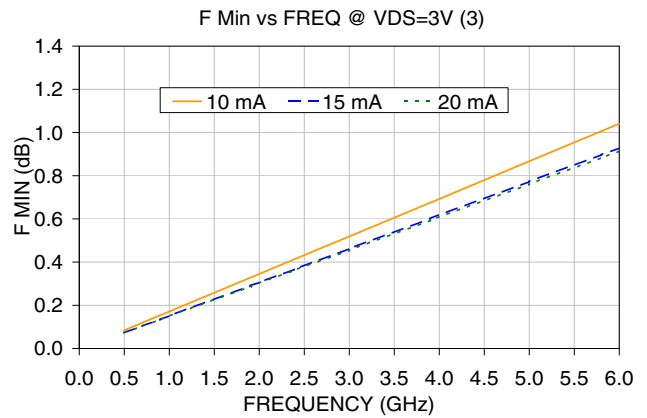
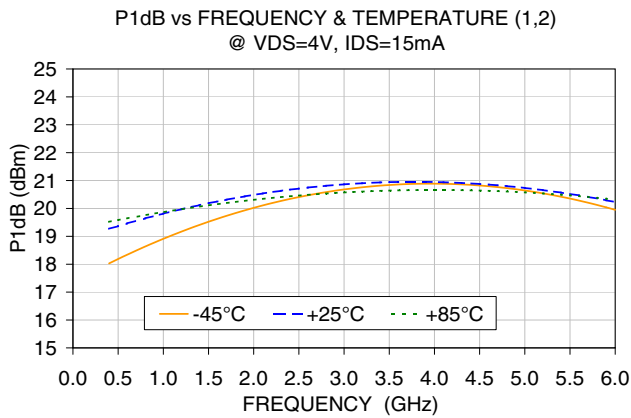


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Reference Plane Location for S and Noise Parameters *(see data in pages 8-11)*
(Refer to Application Note AN-60-040)

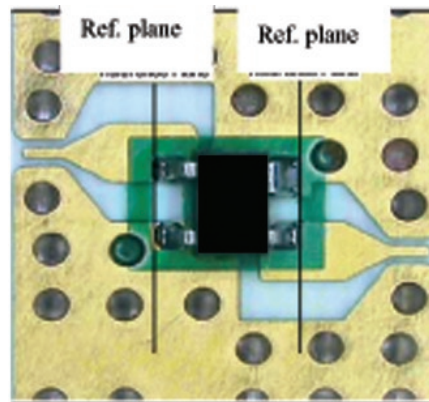


Fig 3. Reference Plane Location

Notes:

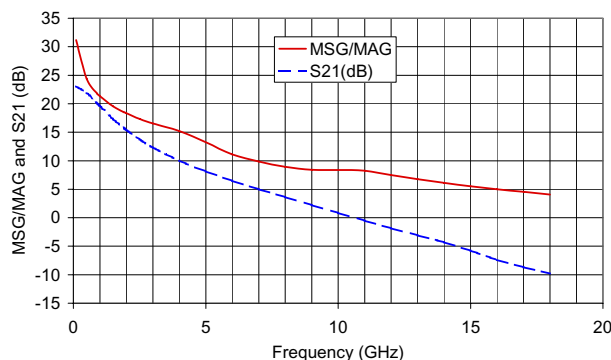
Noise parameters were measured over 0.5 to 6 GHz by Modelithics® using a solid state tuner-based noise parameter (NP) test system available from Maury Microwave. F Min, optimum source reflection coefficient and noise resistance values are calculated values based on a set of measurements made at approximately 16 different impedances. Some data smoothing was applied to arrive at the presented data set.

S-parameters were measured by Modelithics® on an Anritsu Lightning vector network analyzer over 0.1 to 18GHz using 350um pitch RF probes from GGB industries combined with customized thru-reflect-line (TRL) calibration standards. The reference plane is at the device package leads, as shown in the picture.

Typical S-parameters, $V_{DS}=3V$ and $I_{DS}=10\text{ mA}$ (Fig. 3)

Freq. (GHz)	S11		S21			S12		S22		MSG/MAG (dB)
	Mag.	Ang.	Mag.	Mag (dB)	Ang.	Mag.	Ang.	Mag.	Ang.	
0.1	1.00	-12.2	14.19	23.04	172.4	0.011	82.7	0.74	-7.85	31.2
0.5	0.93	-56.7	12.42	21.88	142.3	0.045	58.6	0.65	-34.99	24.4
0.9	0.84	-91.8	10.06	20.05	119.5	0.067	40.7	0.53	-55.17	21.8
1.0	0.82	-99.5	9.53	19.58	114.6	0.070	37.2	0.50	-59.64	21.3
1.5	0.75	-130.8	7.37	17.35	94.6	0.082	24.0	0.39	-76.86	19.6
1.9	0.72	-150.3	6.14	15.77	81.6	0.086	16.5	0.33	-88.14	18.6
2.0	0.71	-154.6	5.89	15.40	78.7	0.086	14.8	0.31	-90.74	18.3
2.5	0.70	-173.7	4.87	13.75	65.2	0.090	8.1	0.26	-102.59	17.3
3.0	0.69	170.0	4.14	12.33	53.1	0.092	2.9	0.22	-114.08	16.5
4.0	0.69	142.6	3.16	10.00	30.9	0.095	-5.3	0.17	-139.34	15.2
5.0	0.71	119.4	2.55	8.11	10.3	0.100	-12.6	0.15	-169.48	13.2
6.0	0.73	99.1	2.11	6.49	-9.2	0.107	-19.0	0.16	157.38	11.1
7.0	0.76	81.2	1.78	5.01	-28.0	0.114	-26.3	0.19	127.43	9.8
8.0	0.79	65.0	1.52	3.62	-46.1	0.122	-33.8	0.25	103.16	9.0
9.0	0.83	49.8	1.29	2.23	-63.7	0.130	-42.9	0.32	82.75	8.4
10.0	0.86	35.3	1.10	0.86	-81.0	0.136	-53.0	0.40	64.70	8.4
11.0	0.89	21.8	0.94	-0.53	-97.4	0.141	-63.9	0.48	48.81	8.2
12.0	0.90	9.3	0.81	-1.86	-112.9	0.145	-74.8	0.55	34.57	7.5
13.0	0.92	-2.7	0.70	-3.10	-127.9	0.147	-86.1	0.61	21.82	6.8
14.0	0.93	-13.7	0.61	-4.31	-141.8	0.149	-96.9	0.66	9.90	6.1
15.0	0.94	-22.2	0.51	-5.78	-152.9	0.144	-105.5	0.72	-0.66	5.5
16.0	0.95	-29.7	0.43	-7.39	-162.9	0.135	-113.6	0.77	-10.14	5.0
17.0	0.95	-38.1	0.37	-8.67	-173.4	0.129	-122.1	0.80	-19.83	4.5
18.0	0.94	-47.2	0.32	-9.80	175.6	0.127	-131.4	0.82	-29.34	4.1

MAXIMUM STABLE GAIN (MSG)/MAXIMUM AVAILABLE GAIN (MAG) vs. FREQUENCY



Typical Noise Parameters, $V_{DS}=3V$ and $I_{DS}=10\text{ mA}$ (Fig. 3)

Freq. (GHz)	F Min. (dB)	Γ_{Opt} (Magnitude)	Γ_{Opt} (Angle)	Rn/50	Ga
					Associated Gain (dB)
0.5	0.084	0.38	24.24	0.09	25.8
0.7	0.119	0.39	34.11	0.08	23.9
0.9	0.154	0.41	43.86	0.08	22.2
1.0	0.171	0.41	48.68	0.07	21.4
1.9	0.328	0.47	90.69	0.05	16.5
2.0	0.345	0.48	95.20	0.05	16.1
2.4	0.415	0.50	112.92	0.04	14.8
3.0	0.519	0.52	138.54	0.04	13.3
3.9	0.675	0.56	174.83	0.06	11.8
5.0	0.867	0.58	-144.30	0.09	10.7
5.8	1.006	0.58	-116.99	0.14	10.0
6.0	1.041	0.58	-110.48	0.15	9.8

Notes:
 F Min.: Minimum Noise Figure
 Γ_{Opt} : Optimum Source Reflection Coefficient
 Rn: Equivalent noise resistance



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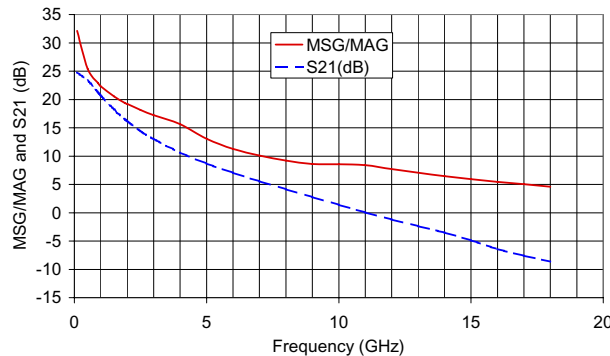
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Typical S-parameters, $V_{DS}=3V$ and $I_{DS}=15\text{ mA}$ (Fig. 3)

Freq. (GHz)	S11		S21			S12		S22		MSG/MAG (dB)
	Mag.	Ang.	Mag.	Mag (dB)	Ang.	Mag.	Ang.	Mag.	Ang.	
0.1	1.00	-13.6	17.40	24.81	171.4	0.011	83.4	0.68	-9.16	32.1
0.5	0.91	-62.5	14.72	23.36	139.0	0.042	56.7	0.58	-40.65	25.4
0.9	0.81	-98.9	11.49	21.21	115.8	0.060	39.5	0.46	-62.99	22.8
1.0	0.79	-106.8	10.81	20.68	111.1	0.063	36.6	0.43	-67.85	22.3
1.5	0.73	-137.6	8.15	18.23	91.7	0.072	25.2	0.32	-86.89	20.5
1.9	0.70	-156.3	6.72	16.55	79.3	0.077	19.2	0.27	-99.60	19.4
2.0	0.69	-160.4	6.44	16.17	76.5	0.077	17.9	0.26	-102.70	19.2
2.5	0.68	-178.8	5.28	14.45	63.6	0.081	12.7	0.21	-116.80	18.1
3.0	0.67	165.7	4.47	13.00	52.0	0.084	8.3	0.18	-130.81	17.2
4.0	0.68	139.5	3.39	10.61	30.5	0.092	0.8	0.15	-161.56	15.7
5.0	0.70	117.1	2.72	8.70	10.6	0.101	-6.6	0.14	165.01	13.1
6.0	0.72	97.4	2.25	7.05	-8.4	0.110	-14.2	0.17	134.79	11.3
7.0	0.76	79.9	1.90	5.56	-26.8	0.120	-22.8	0.21	109.98	10.1
8.0	0.79	64.0	1.62	4.17	-44.4	0.129	-32.1	0.27	90.15	9.2
9.0	0.82	49.1	1.38	2.77	-61.5	0.136	-42.2	0.34	72.63	8.6
10.0	0.86	34.7	1.18	1.42	-78.3	0.142	-53.0	0.42	56.76	8.6
11.0	0.88	21.3	1.01	0.06	-94.4	0.145	-64.1	0.49	42.40	8.4
12.0	0.90	9.0	0.87	-1.21	-109.7	0.148	-75.2	0.55	29.29	7.7
13.0	0.92	-3.0	0.76	-2.38	-124.5	0.150	-86.5	0.61	17.47	7.1
14.0	0.93	-13.9	0.67	-3.50	-138.3	0.151	-97.3	0.66	6.31	6.5
15.0	0.94	-22.5	0.57	-4.88	-149.6	0.145	-106.0	0.71	-3.44	5.9
16.0	0.95	-29.9	0.48	-6.40	-159.6	0.136	-114.0	0.76	-12.29	5.5
17.0	0.95	-38.4	0.42	-7.61	-170.5	0.131	-122.3	0.79	-21.56	5.0
18.0	0.94	-47.6	0.37	-8.64	178.3	0.128	-131.3	0.81	-30.73	4.6

MAXIMUM STABLE GAIN (MSG)/MAXIMUM AVAILABLE GAIN (MAG) vs. FREQUENCY



Typical Noise Parameters, $V_{DS}=3V$ and $I_{DS}=15\text{ mA}$ (Fig. 3)

Freq. (GHz)	F Min. (dB)	Γ Opt (Magnitude)	Γ Opt (Angle)	Rn/50	Ga
					Associated Gain (dB)
0.5	0.073	0.38	23.41	0.07	26.4
0.7	0.104	0.39	33.53	0.07	24.4
0.9	0.135	0.40	43.52	0.06	22.7
1.0	0.151	0.40	48.46	0.06	21.9
1.9	0.291	0.44	91.46	0.04	17.1
2.0	0.306	0.44	96.07	0.04	16.7
2.4	0.368	0.46	114.17	0.04	15.4
3.0	0.462	0.48	140.33	0.04	13.9
3.9	0.602	0.51	177.31	0.05	12.4
5.0	0.773	0.54	-141.16	0.09	11.1
5.8	0.897	0.56	-113.50	0.13	10.4
6.0	0.928	0.57	-106.92	0.14	10.2

Notes:
 F Min.: Minimum Noise Figure
 Γ Opt: Optimum Source Reflection Coefficient
 Rn: Equivalent noise resistance



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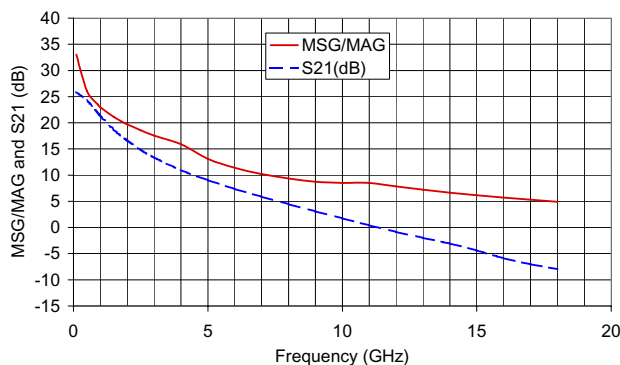
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Typical S-parameters, $V_{DS}=3V$ and $I_{DS}=20\text{ mA}$ (Fig. 3)

Freq. (GHz)	S11		S21			S12		S22		MSG/MAG (dB)
	Mag.	Ang.	Mag.	Mag (dB)	Ang.	Mag.	Ang.	Mag.	Ang.	
0.1	1.00	-14.6	19.72	25.90	170.8	0.010	82.4	0.64	-10.31	33.1
0.5	0.90	-66.4	16.28	24.23	136.8	0.040	56.7	0.53	-44.84	26.1
0.9	0.79	-103.5	12.41	21.87	113.5	0.055	39.8	0.41	-68.82	23.5
1.0	0.77	-111.4	11.61	21.30	108.8	0.058	36.6	0.38	-74.04	23.0
1.5	0.71	-141.8	8.63	18.72	89.9	0.067	26.7	0.29	-94.72	21.1
1.9	0.69	-160.0	7.08	17.00	77.9	0.071	21.3	0.24	-108.79	20.0
2.0	0.68	-164.0	6.76	16.60	75.2	0.072	20.5	0.23	-112.22	19.7
2.5	0.67	178.2	5.53	14.85	62.7	0.077	15.8	0.19	-128.11	18.6
3.0	0.67	163.2	4.66	13.37	51.4	0.082	12.0	0.16	-143.89	17.6
4.0	0.67	137.6	3.54	10.97	30.3	0.091	4.6	0.14	-177.41	15.9
5.0	0.69	115.8	2.83	9.04	10.7	0.101	-3.3	0.15	150.47	13.1
6.0	0.72	96.4	2.34	7.38	-8.0	0.113	-11.8	0.18	123.60	11.4
7.0	0.75	79.1	1.97	5.87	-26.1	0.123	-21.4	0.23	101.71	10.2
8.0	0.79	63.4	1.67	4.47	-43.4	0.133	-31.1	0.29	83.79	9.4
9.0	0.82	48.6	1.43	3.08	-60.2	0.140	-41.8	0.36	67.59	8.7
10.0	0.85	34.3	1.22	1.73	-76.8	0.145	-53.0	0.43	52.50	8.5
11.0	0.88	21.0	1.05	0.40	-92.6	0.148	-64.2	0.50	38.81	8.5
12.0	0.90	8.7	0.91	-0.85	-107.7	0.149	-75.5	0.56	26.25	7.8
13.0	0.92	-3.2	0.80	-1.99	-122.4	0.151	-86.8	0.61	14.83	7.2
14.0	0.93	-14.1	0.70	-3.06	-136.2	0.152	-97.5	0.65	4.04	6.7
15.0	0.94	-22.7	0.60	-4.39	-147.4	0.147	-106.1	0.70	-5.28	6.1
16.0	0.95	-30.1	0.51	-5.85	-157.5	0.137	-114.0	0.75	-13.74	5.7
17.0	0.95	-38.7	0.45	-7.01	-168.4	0.131	-122.4	0.78	-22.81	5.3
18.0	0.94	-47.9	0.40	-7.98	-179.9	0.129	-131.5	0.80	-31.83	4.9

MAXIMUM STABLE GAIN (MSG)/MAXIMUM AVAILABLE GAIN (MAG) vs. FREQUENCY



Typical Noise Parameters, $V_{DS}=3V$ and $I_{DS}=20\text{ mA}$ (Fig. 3)

Freq. (GHz)	F Min. (dB)	Γ_{Opt} (Magnitude)	Γ_{Opt} (Angle)	Rn/50	Ga
					Associated Gain (dB)
0.5	0.073	0.39	32.95	0.07	27.9
0.7	0.104	0.40	42.06	0.06	25.5
0.9	0.134	0.40	51.08	0.05	23.6
1.0	0.150	0.40	55.57	0.05	22.7
1.9	0.287	0.41	95.05	0.04	17.6
2.0	0.303	0.42	99.33	0.04	17.2
2.4	0.364	0.43	116.29	0.04	15.8
3.0	0.455	0.44	141.14	0.04	14.2
3.9	0.593	0.46	177.08	0.05	12.6
5.0	0.761	0.50	-141.15	0.09	11.3
5.8	0.883	0.53	-112.27	0.13	10.5
6.0	0.914	0.54	-105.24	0.14	10.3

Notes:
 F Min.: Minimum Noise Figure
 Γ_{Opt} : Optimum Source Reflection Coefficient
 Rn: Equivalent noise resistance



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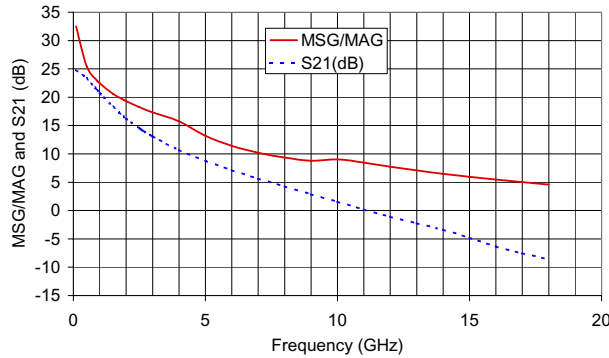
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Typical S-parameters, $V_{DS}=4V$ and $I_{DS}=15\text{ mA}$ (Fig. 3)

Freq. (GHz)	S11		S21			S12		S22		MSG/MAG (dB)
	Mag.	Ang.	Mag.	Mag (dB)	Ang.	Mag.	Ang.	Mag.	Ang.	
0.1	1.00	-13.5	17.35	24.79	171.5	0.010	81.4	0.70	-8.89	32.5
0.5	0.91	-61.9	14.71	23.35	139.3	0.042	56.8	0.59	-39.38	25.4
0.9	0.81	-98.1	11.52	21.23	116.2	0.059	40.4	0.47	-60.91	22.9
1.0	0.79	-106.0	10.86	20.71	111.4	0.062	37.2	0.44	-65.59	22.5
1.5	0.73	-136.9	8.20	18.28	91.9	0.071	25.5	0.33	-83.71	20.6
1.9	0.70	-155.7	6.76	16.60	79.5	0.075	19.3	0.27	-95.59	19.5
2.0	0.69	-159.8	6.48	16.23	76.7	0.076	18.0	0.26	-98.43	19.3
2.5	0.68	-178.2	5.32	14.51	63.8	0.080	12.7	0.21	-111.64	18.2
3.0	0.67	166.2	4.50	13.06	52.2	0.083	8.4	0.18	-124.59	17.3
4.0	0.68	139.9	3.42	10.69	30.7	0.091	1.0	0.14	-153.64	15.7
5.0	0.70	117.5	2.75	8.78	10.7	0.099	-6.0	0.13	172.83	13.2
6.0	0.72	97.8	2.28	7.14	-8.3	0.108	-13.5	0.15	140.56	11.4
7.0	0.75	80.2	1.92	5.65	-26.7	0.118	-22.0	0.20	114.24	10.2
8.0	0.79	64.2	1.63	4.26	-44.4	0.127	-31.2	0.26	93.28	9.3
9.0	0.82	49.3	1.39	2.88	-61.6	0.135	-41.1	0.33	75.10	8.8
10.0	0.85	34.9	1.19	1.54	-78.5	0.141	-52.1	0.40	58.79	9.0
11.0	0.88	21.5	1.02	0.19	-94.7	0.145	-63.1	0.48	44.10	8.5
12.0	0.90	9.2	0.88	-1.09	-110.1	0.148	-74.3	0.54	30.76	7.8
13.0	0.92	-2.8	0.77	-2.27	-125.1	0.151	-85.7	0.60	18.78	7.1
14.0	0.93	-13.8	0.68	-3.41	-139.0	0.152	-96.6	0.65	7.47	6.5
15.0	0.94	-22.4	0.58	-4.81	-150.4	0.146	-105.3	0.71	-2.48	5.9
16.0	0.95	-29.8	0.48	-6.35	-160.6	0.137	-113.2	0.76	-11.45	5.5
17.0	0.95	-38.3	0.42	-7.57	-171.5	0.131	-121.7	0.79	-20.84	5.0
18.0	0.95	-47.5	0.37	-8.63	177.3	0.129	-130.7	0.81	-30.07	4.6

MAXIMUM STABLE GAIN (MSG)/MAXIMUM AVAILABLE GAIN (MAG) vs. FREQUENCY



Typical Noise Parameters, $V_{DS}=4V$ and $I_{DS}=15\text{ mA}$ (Fig. 3)

Freq. (GHz)	F Min. (dB)	Γ Opt (Magnitude)	Γ Opt (Angle)	Rn/50	Ga
					Associated Gain (dB)
0.5	0.072	0.39	24.88	0.08	26.6
0.7	0.103	0.39	34.47	0.07	24.6
0.9	0.134	0.40	43.97	0.06	22.8
1.0	0.149	0.41	48.68	0.06	22.0
1.9	0.287	0.44	89.97	0.04	17.0
2.0	0.302	0.44	94.44	0.04	16.6
2.4	0.363	0.45	112.05	0.04	15.3
3.0	0.455	0.47	137.73	0.04	13.8
3.9	0.592	0.49	174.57	0.05	12.3
5.0	0.761	0.51	-143.11	0.09	11.1
5.8	0.883	0.53	-114.21	0.13	10.3
6.0	0.914	0.53	-107.23	0.14	10.1

Notes:
 F Min.: Minimum Noise Figure
 Γ Opt: Optimum Source Reflection Coefficient
 Rn: Equivalent noise resistance

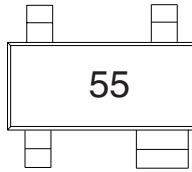


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Product Marking



Additional Detailed Technical Information

Additional information is available on our web site www.minicircuits.com. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: MMM1362

Plastic molded SOT-343 (SC-70) style package, lead finish: matte tin

Suggested Layout for PCB Design: PL-300

Tape & Reel: F90

Characterization Test Board: TB-471+

Environmental Ratings: ENV08T2

ESD Rating

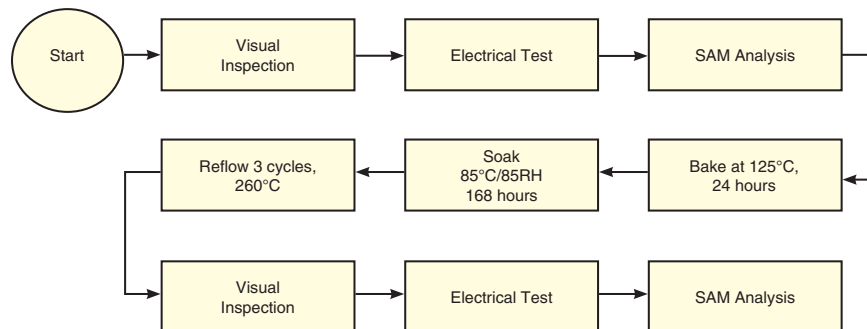
Human Body Model (HBM): Class 1A (250 V to < 500 V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (40 V) in accordance with ANSI/ESD STM 5.2 - 1999

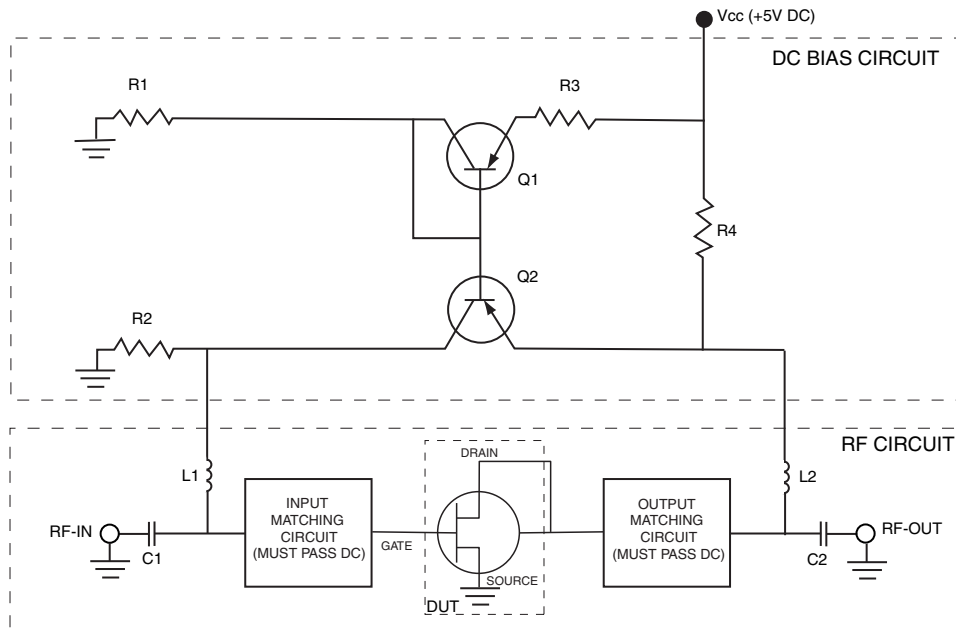
MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020D

MSL Test Flow Chart



Recommended Application Circuit



VDS, V (nom)	3	4
IDS, mA (nom)	15mA	15mA
R1	4320Ω	4320Ω
R2	4320Ω	4320Ω
R3	3570Ω	1210Ω
R4	133Ω	68.1Ω
Q1	MMBT3906*	MMBT3906*
Q2	MMBT3906*	MMBT3906*
C1	0.01μF	0.01μF
C2	0.01μF	0.01μF
L1**	840nH	840nH
L2**	840nH	840nH

* Fairchild Semiconductor™ part number
 ** Piconics™ part number CC45T47K240G5

Optimized Amplifier Circuits

For band specific, drop-in modules, and as an alternative to designing circuits, please refer to Mini-Circuits TAMP and RAMP series models which are based upon SAV/TAV E-PHEMT's and include all DC blocking, bias, matching and stabilization circuitry, without need for any external components.



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